NSN 5962-01-355-9334

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Overall Lengtl	ւ։
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Between 2.370 inches and 2.430 inches

Overall Height:

Between 0.225 inches and 0.365 inches

Body Length:

Between 2.370 inches and 2.430 inches

Body Width:

Between 0.550 inches and 0.610 inches

Body Height:

Between 0.130 inches and 0.170 inches

Maximum Power Dissipation Rating:

1.5 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bidirectional and high speed and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

45 input

Criticality Code Justification:

Feat

Current Rating Per Characteristic:

50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Product Name:

Dual-port rams

Voltage Rating And Type Per Characteristic:

4.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds access

Memory Device Type:

Ram

Special Features:

Item must comply with requirements of defense electronics supply center production standard no. L04445; for navy nuclear propulsion plant products only

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

48 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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